



DNB64

Rectifier Diode

Replaces January 2000 version, DS4180-5.0

DS4180-6.0 August 2001

FEATURES

- Double Side Cooling
- High Surge Capability

APPLICATIONS

- Rectification
- Freewheel Diode
- DC Motor Control
- Power Supplies
- Welding
- Battery Chargers

VOLTAGE RATINGS

Type Number	Repetitive Peak Reverse Voltage V_{RRM} V	Conditions
DNB64 36	3600	$V_{RSM} = V_{RRM} + 100V$
DNB64 34	3400	
DNB64 32	3200	
DNB64 30	3000	
DNB64 28	2800	
DNB64 26	2600	

Lower voltage grades available.

KEY PARAMETERS

V_{RRM}	3600V
$I_{F(AV)}$	3019A
I_{FSM}	27000A

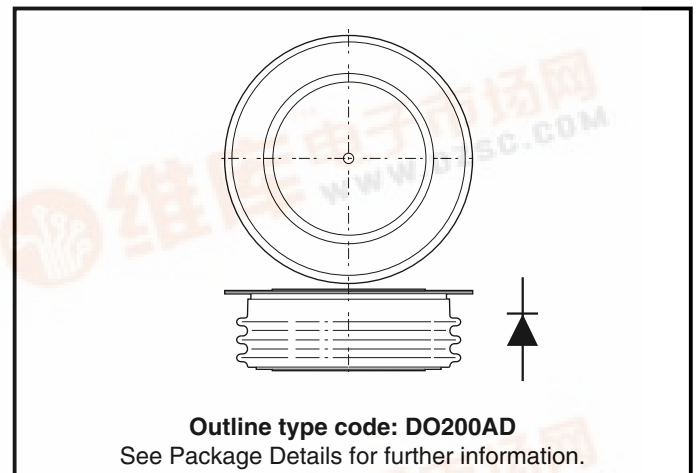


Fig. 1 Package outline

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table, e.g.:

DNB64 34

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.

CURRENT RATINGS

 $T_{case} = 75^{\circ}\text{C}$ unless otherwise stated

Symbol	Parameter	Conditions	Max.	Units
Double Side Cooled				
$I_{F(AV)}$	Mean forward current	Half wave resistive load	3019	A
$I_{F(RMS)}$	RMS value	-	4741	A
I_F	Continuous (direct) forward current	-	4414	A
Single Side Cooled (Anode side)				
$I_{F(AV)}$	Mean forward current	Half wave resistive load	2280	A
$I_{F(RMS)}$	RMS value	-	3581	A
I_F	Continuous (direct) forward current	-	3182	A

 $T_{case} = 100^{\circ}\text{C}$ unless otherwise stated

Symbol	Parameter	Conditions	Max.	Units
Double Side Cooled				
$I_{F(AV)}$	Mean forward current	Half wave resistive load, $T_{case} = 100^{\circ}\text{C}$	2530	A
$I_{F(RMS)}$	RMS value	$T_{case} = 100^{\circ}\text{C}$	3980	A
I_F	Continuous (direct) forward current	$T_{case} = 100^{\circ}\text{C}$	3635	A
Single Side Cooled (Anode side)				
$I_{F(AV)}$	Mean forward current	Half wave resistive load, $T_{case} = 100^{\circ}\text{C}$	1655	A
$I_{F(RMS)}$	RMS value	$T_{case} = 100^{\circ}\text{C}$	2600	A
I_F	Continuous (direct) forward current	$T_{case} = 100^{\circ}\text{C}$	2280	A

SURGE RATINGS

Symbol	Parameter	Conditions	Max.	Units
I_{FSM}	Surge (non-repetitive) forward current	10ms half sine; $T_{case} = 175^{\circ}C$ $V_R = 50\% V_{RRM} - 1/4$ sine	21.5	kA
I^2t	I^2t for fusing		2.33×10^6	A^2s
I_{FSM}	Surge (non-repetitive) forward current	10ms half sine; $T_{case} = 175^{\circ}C$ $V_R = 0$	27.0	kA
I^2t	I^2t for fusing		3.645×10^6	A^2s

THERMAL AND MECHANICAL DATA

Symbol	Parameter	Conditions		Min.	Max.	Units
$R_{th(j-c)}$	Thermal resistance - junction to case	Double side cooled	dc	-	0.013	$^{\circ}C/W$
		Single side cooled	Anode dc	-	0.025	$^{\circ}C/W$
			Cathode dc	-	0.027	$^{\circ}C/W$
$R_{th(c-h)}$	Thermal resistance - case to heatsink	Clamping force 45.0kN with mounting compound	Double side	-	0.003	$^{\circ}C/W$
			Single side	-	0.006	$^{\circ}C/W$
T_{vj}	Virtual junction temperature	Forward (conducting)		-	185	$^{\circ}C$
		Reverse (blocking)		-	175	$^{\circ}C$
T_{stg}	Storage temperature range			-55	200	$^{\circ}C$
-	Clamping force			40.0	48.0	kN

CHARACTERISTICS

Symbol	Parameter	Conditions	Typ.	Max.	Units
V_{FM}	Forward voltage	At 1500A peak, $T_{case} = 25^{\circ}C$	-	1.1	V
I_{RRM}	Peak reverse current	At V_{RRM} , $T_{case} = 175^{\circ}C$	-	100	mA
Q_S	Total stored charge	$I_F = 1000A$, $di_{RR}/dt = 5A/\mu s$ $T_{case} = 125^{\circ}C$, $V_R = 100V$	4000	-	μC
I_{RR}	Peak recovery current		150	-	A
t_{rr}	Reverse recovery time		30	-	μs
V_{TO}	Threshold voltage	At $T_{vj} = 175^{\circ}C$	-	0.86	V
r_T	Slope resistance	At $T_{vj} = 175^{\circ}C$	-	0.2	m Ω

CURVES

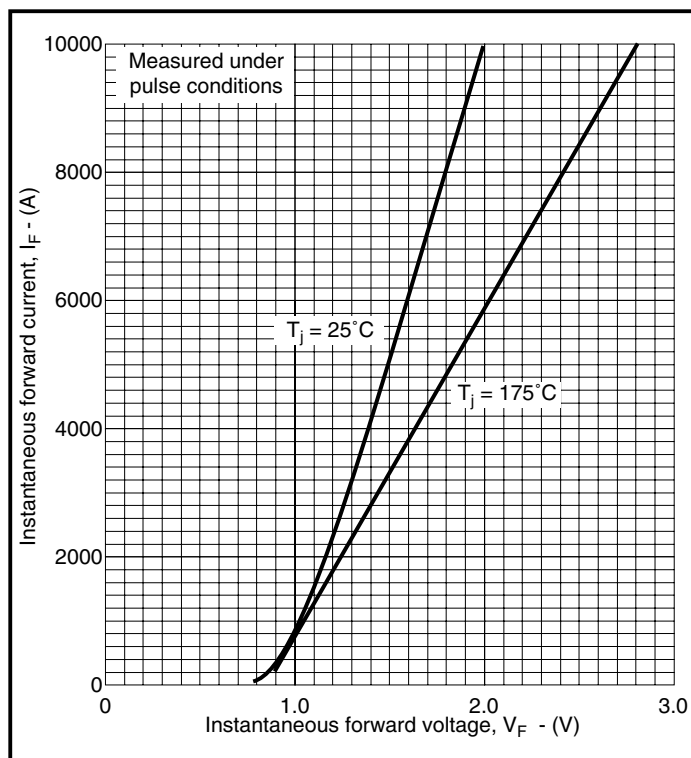


Fig.2 Maximum (limit) forward characteristics

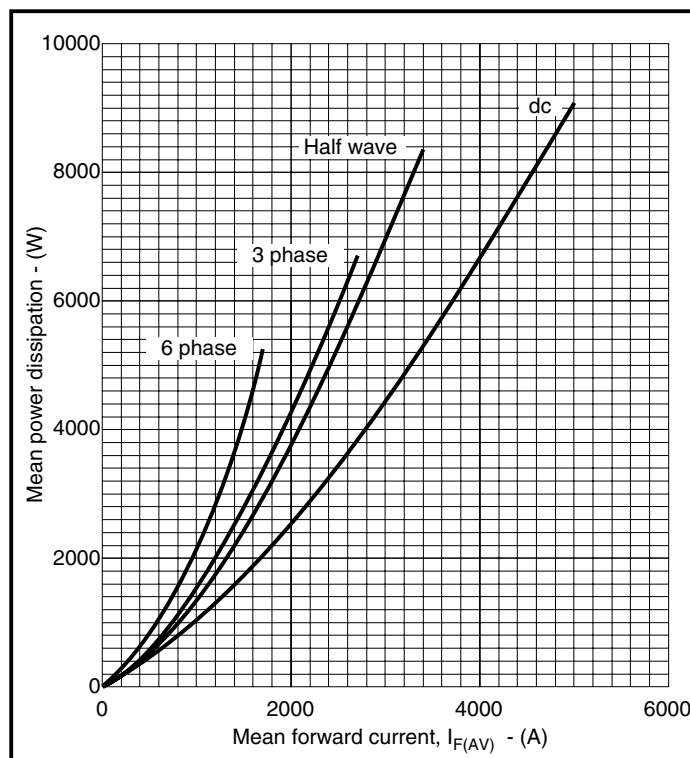


Fig.3 Dissipation curves

V_{FM} Equation:-

$$V_{FM} = A + B \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

Where

$$A = 0.506497$$

$$B = 0.070975$$

$$C = 0.000219$$

$$D = -0.00553$$

these values are valid for $T_j = 125^{\circ}C$ for I_F 500A to 10000A

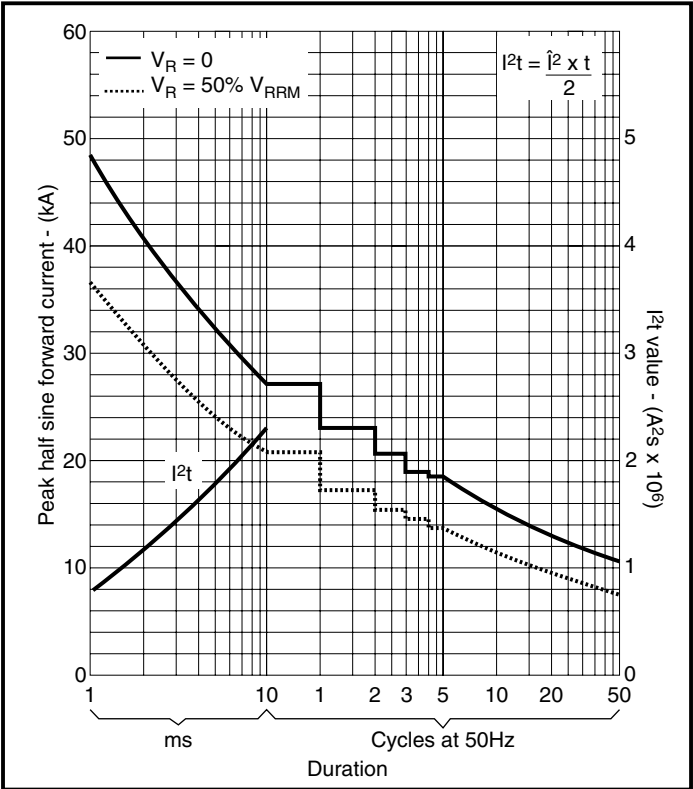


Fig.4 Surge (non-repetitive) forward current vs time
(at $T_{case} 175^\circ C$)

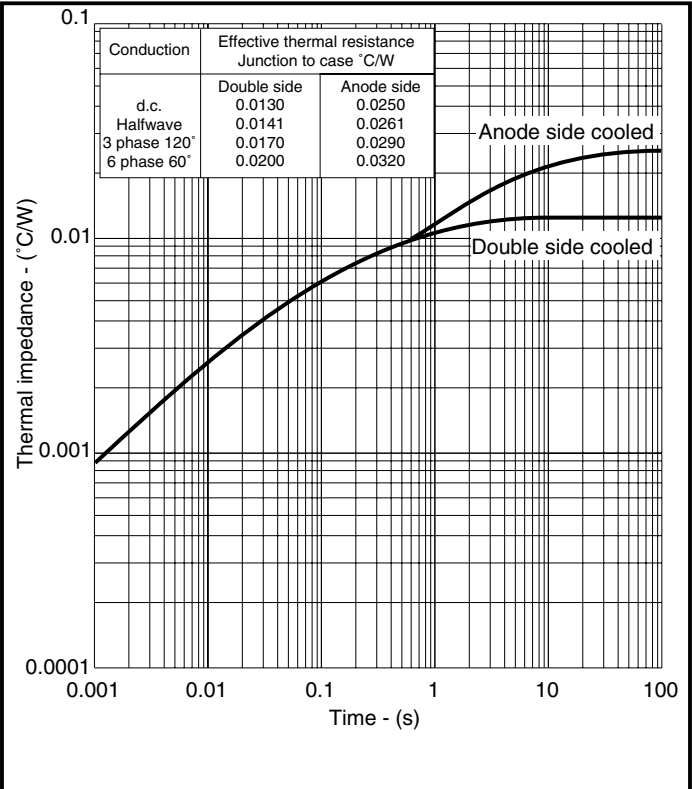
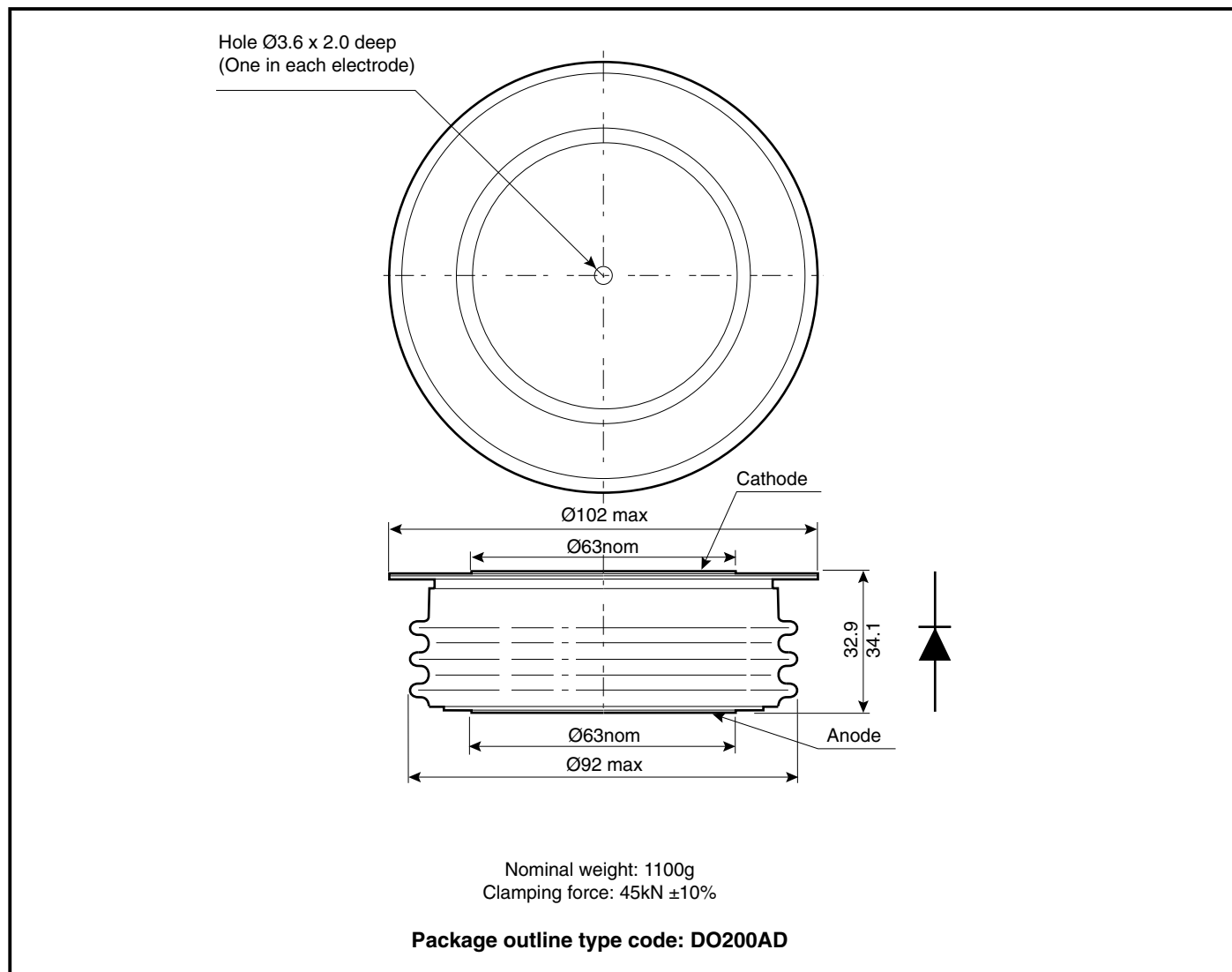


Fig.5 Maximum (limit) transient thermal impedance - junction to case

PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise.
DO NOT SCALE.

**Note:**

1. Package maybe supplied with pins and/or tags.

POWER ASSEMBLY CAPABILITY

The Power Assembly group was set up to provide a support service for those customers requiring more than the basic semiconductor, and has developed a flexible range of heatsink and clamping systems in line with advances in device voltages and current capability of our semiconductors.

We offer an extensive range of air and liquid cooled assemblies covering the full range of circuit designs in general use today. The Assembly group offers high quality engineering support dedicated to designing new units to satisfy the growing needs of our customers.

Using the latest CAD methods our team of design and applications engineers aim to provide the Power Assembly Complete Solution (PACs).

HEATSINKS

The Power Assembly group has its own proprietary range of extruded aluminium heatsinks which have been designed to optimise the performance of Dynex semiconductors. Data with respect to air natural, forced air and liquid cooling (with flow rates) is available on request.

For further information on device clamps, heatsinks and assemblies, please contact your nearest sales representative or Customer Services.

Stresses above those listed in this data sheet may cause permanent damage to the device. In extreme conditions, as with all semiconductors, this may include potentially hazardous rupture of the package. Appropriate safety precautions should always be followed.



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